Schottky Barrier on Gallium Oxide

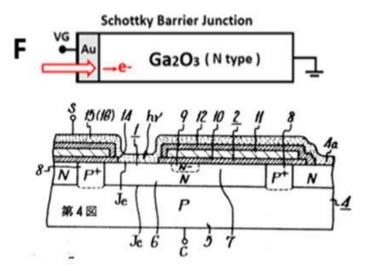


Fig. 6: Cross sectional view of Type F Schottky barrier photo sensor.

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The Cross sectional view the type F device

of the Schottky barrier photo sensor

is also shown in the figure 6.

The PN junction leakage is dependent on

the minority carrier density of

the semiconductor material itself.

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